



Vishay Telefunken

MOSMIC® for TV-Tuner Prestage with 5 V Supply Voltage

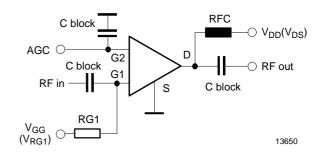
MOSMIC - MOS Monolithic Integrated Circuit

Electrostatic sensitive device. Observe precautions for handling.



Applications

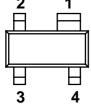
Low noise gain controlled input stages in UHF-and VHF- tuner with 5 V supply voltage.



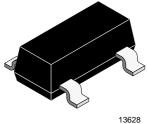
Features

- Easy Gate 1 switch-off with PNP switching transistors inside PLL
- High AGC-range
- Integrated gate protection diodes

- Low noise figure
- High gain
- Improved cross modulation at gain reduction
- SMD package

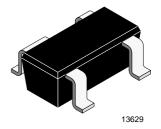


Plastic case (SOT 143)



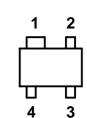
3 4 S505T Marking: 505

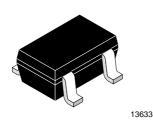
1 = Source, 2 = Drain, 3 = Gate 2, 4 = Gate 1



S505TR Marking: 55R Plastic case (SOT 143R)

1 = Source, 2 = Drain, 3 = Gate 2, 4 = Gate 1





S505TRW Marking: W05
Plastic case (SOT 343R)
1 = Source, 2 = Drain, 3 = Gate 2, 4 = Gate 1

S505T/S505TR/S505TRW

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Absolute Maximum Ratings

 $T_{amb} = 25$ °C, unless otherwise specified

Parameter	Test Conditions	Symbol	Value	Unit
Drain - source voltage		V _{DS}	8	V
Drain current		I _D	30	mA
Gate 1/Gate 2 - source peak current		±I _{G1/G2SM}	10	mΑ
Gate 1/Gate 2 - source voltage		±V _{G1/G2SM}	6	V
Total power dissipation	T _{amb} ≤ 60 °C	P _{tot}	200	mW
Channel temperature		T _{Ch}	150	°C
Storage temperature range		T _{stg}	-55 to +150	°C

Maximum Thermal Resistance

 $T_{amb} = 25$ °C, unless otherwise specified

Parameter	Test Conditions	Symbol	Value	Unit
Channel ambient	on glass fibre printed board (25 x 20 x 1.5) mm ³	R _{thChA}	450	K/W
	plated with 35μm Cu			

Electrical DC Characteristics

 $T_{amb} = 25$ °C, unless otherwise specified

Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
Drain - source breakdown voltage	$I_D = 10 \mu A, V_{G1S} = V_{G2S} = 0$	V _{(BR)DSS}	15			V
Gate 1 - source breakdown voltage	$\pm I_{G1S} = 10 \text{ mA}, V_{G2S} = V_{DS} = 0$	±V _{(BR)G1SS}	7		10	V
Gate 2 - source breakdown voltage	$\pm I_{G2S} = 10 \text{ mA}, V_{G1S} = V_{DS} = 0$	±V _{(BR)G2SS}	7		10	V
Gate 1 - source leakage current	$+V_{G1S} = 5 \text{ V}, V_{G2S} = V_{DS} = 0$	+I _{G1SS}			20	nA
Gate 2 - source leakage current	$\pm V_{G2S} = 5 \text{ V}, V_{G1S} = V_{DS} = 0$	±I _{G2SS}			20	nA
Drain - source op- erating current	$V_{DS} = V_{RG1} = 5 \text{ V}, V_{G2S} = 4 \text{ V}, R_{G1} = 220 \text{ k}\Omega$	I _{DSO}	10	13	18	mA
Gate 1 - source cut-off voltage	$V_{DS} = 5 \text{ V}, V_{G2S} = 4, I_{D} = 20 \mu\text{A}$	V _{G1S(OFF)}	0.4		1.2	V
Gate 2 - source cut-off voltage	$V_{DS} = V_{RG1} = 5 \text{ V}, R_{G1} = 220 \text{ k}\Omega, I_D = 20 \mu\text{A}$	V _{G2S(OFF)}		1.0		V

Remark on improving intermodulation behavior:

By setting R_{G1} smaller than 220 $k\Omega$, e.g. 180 $k\Omega$, typical value of I_{DSO} will raise and improved intermodulation behavior will be performed.



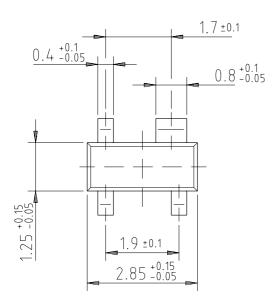
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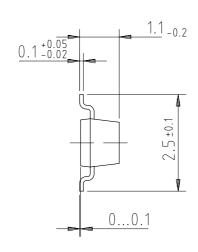
Electrical AC Characteristics

 V_{DS} = 5 V, V_{G2S} = 4 V, I_{D} = 13 mA, f = 1 MHz , T_{amb} = 25 °C, unless otherwise specified

Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
Forward transadmittance		y _{21s}	28		35	mS
Gate 1 input capacitance		C _{issg1}		2.3	2.7	pF
Feedback capacitance		C _{rss}		25		fF
Output capacitance		Coss		1.1		pF
Power gain	$G_S = 2 \text{ mS}, G_L = 0.5 \text{ mS}, f = 200 \text{ MHz}$	G _{ps}		28		dB
	$G_S = 3.3 \text{ mS}, G_L = 1 \text{ mS}, f = 800 \text{ MHz}$	G _{ps}	17	21		dB
AGC range	$V_{DS} = 5 \text{ V}, V_{G2S} = 1 \text{ to 4 V}, f = 800 \text{ MHz}$	ΔG_{ps}	45			dB
Noise figure	$G_S = 2 \text{ mS}, G_L = 0.5 \text{ mS}, f = 200 \text{ MHz}$	F		1		dB
	$G_S = 3.3 \text{ mS}, G_L = 1 \text{ mS}, f = 800 \text{ MHz}$	F		1.3		dB

Dimensions of S505T in mm





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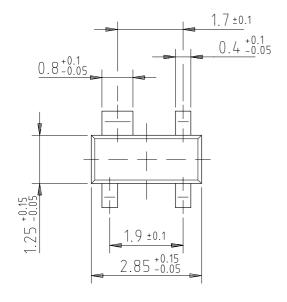
technical drawings according to DIN specifications

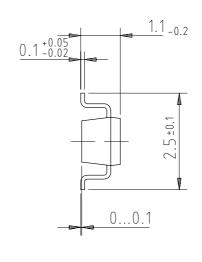
S505T/S505TR/S505TRW

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Dimensions of S505TR in mm



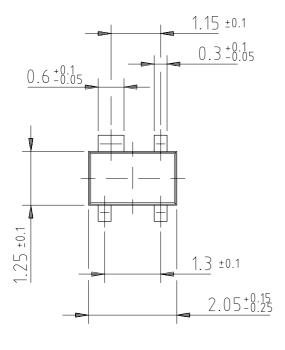


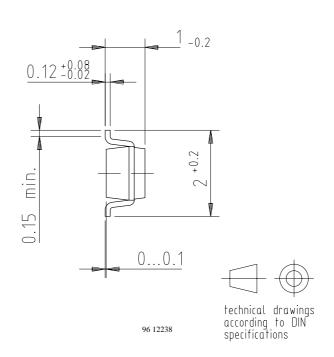


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Dimensions of S505TRW in mm





S505T/S505TR/S505TRW



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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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Document Number 85044 www.vishav.com Rev. 5, 05-Jun-01 5 (5)